

January 7, 1998

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AXIAL LEADED HERMETICALLY SEALED SUPERFAST RECTIFIER DIODE

- Very low reverse recovery time
- Hermetically sealed in Metoxilite fused metal oxide
- Low switching losses
- Low forward voltage drop
- Soft, non-snap off, recovery characteristics

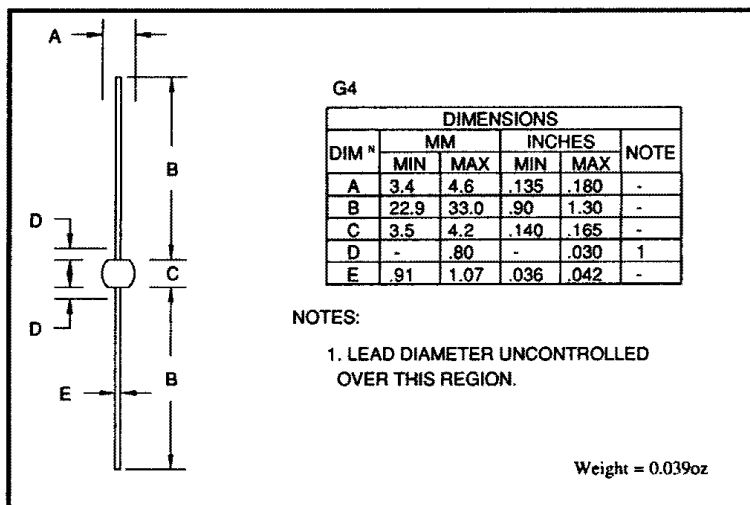
QUICK REFERENCE DATA

- $V_R = 50 - 150V$
- $I_F = 5.0A$
- $t_{rr} = 30nS$
- $V_F = 0.97V$

ABSOLUTE MAXIMUM RATINGS (@ 25°C unless otherwise specified)

	Symbol	1N6079 5FF05	1N6080 5FF10	1N6081 5FF15	Unit
Working reverse voltage	V_{RWM}	50	100	150	V
Repetitive reverse voltage	V_{RRM}	50	100	150	V
Average forward current (@ 55°C, lead length 0.375")	$I_{F(av)}$	←———— 5.0 —————→			A
Repetitive surge current (@ 55°C in free air, lead length 0.375")	I_{FRM}	←———— 24 —————→			A
Non-repetitive surge current ($t_p = 8.3mS$, @ V_R & T_{jmax})	I_{FSM}	←———— 175 —————→			A
Storage temperature range	T_{STG}	←———— -65 to +150 —————→			°C
Operating temperature range	T_{OP}	←———— -65 to +150 —————→			°C

MECHANICAL



These products are qualified to MIL-S-19500/503.

They can be supplied fully released as JAN, JANTX, and JANTXV versions.

These products are qualified in Europe to DEF STAN 59-61 (PART 80)/030 available to F and FX levels.

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ELECTRICAL CHARACTERISTICS (@ 25°C unless otherwise specified)

	Symbol	1N6079 5FF05	1N6080 5FF10	1N6081 5FF15	Unit
Average forward current max. T _A = 55°C for sine wave	I _{F(AV)}	← 2.0 →			A
Average forward current max. T _L = 70°C; L = 0"	I _{F(AV)}	← 12.0 →			A
T _L = 55°C; L = 3/8"	I _{F(AV)}	← 4.8 →			A
for sine wave	I _{F(AV)}	← 5.0 →			A
for square wave	I _{F(AV)}	← 5.0 →			A
I ² t for fusing (t = 8.3mS) max.	I ² t	← 127 →			A ² S
Forward voltage drop max. @ I _F = 5.0A, T _j = 25°C	V _F	← 0.97 →			V
Reverse current max. @ V _{RWM} , T _j = 25°C	I _R	← 10 →			μA
@ V _{RWM} , T _j = 100°C	I _R	← 500 →			μA
Reverse recovery time max. 0.5A I _F to 1.0A I _R . Recovers to 0.25A I _{RR} .	t _{rr}	← 30 →			nS
Junction capacitance typ. @ V _R = 5V, f = 1MHz	C _j	← 230 →			pF

THERMAL CHARACTERISTICS

	Symbol	1N6079 5FF05	1N6080 5FF10	1N6081 5FF15	Unit
Thermal resistance - junction to lead Lead length = 0.375"	R _{θJL}	← 23.5 →			°C/W
Lead length = 0.0"	R _{θJL}	← 5 →			°C/W
Thermal resistance - junction to amb. on 0.06" thick pcb. 1 oz. copper.	R _{θJA}	← 75 →			°C/W

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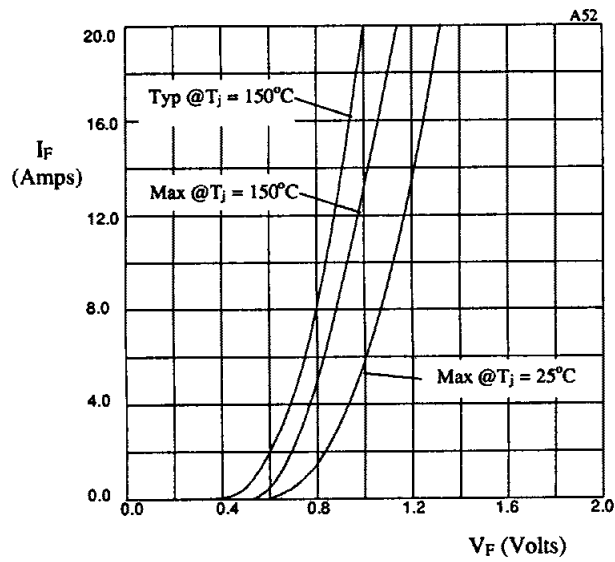


Fig 1. Forward voltage drop as a function of forward current

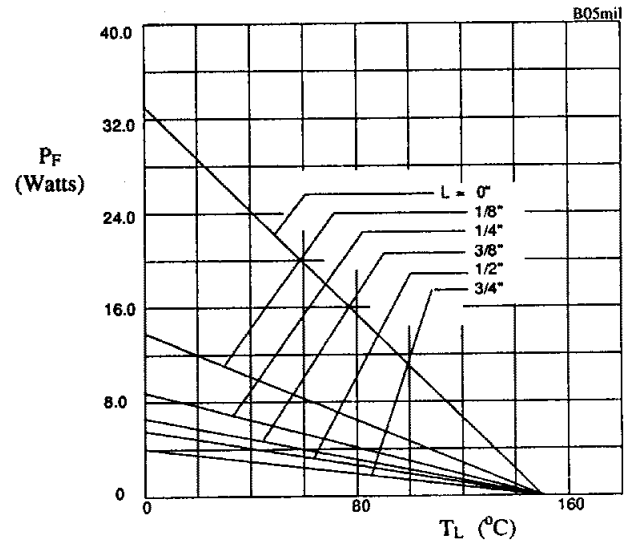


Fig 2. Maximum power versus lead temperature

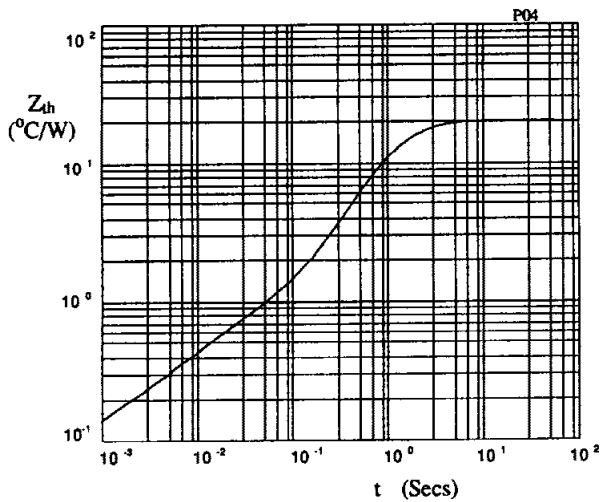


Fig 3. Transient thermal impedance characteristic.

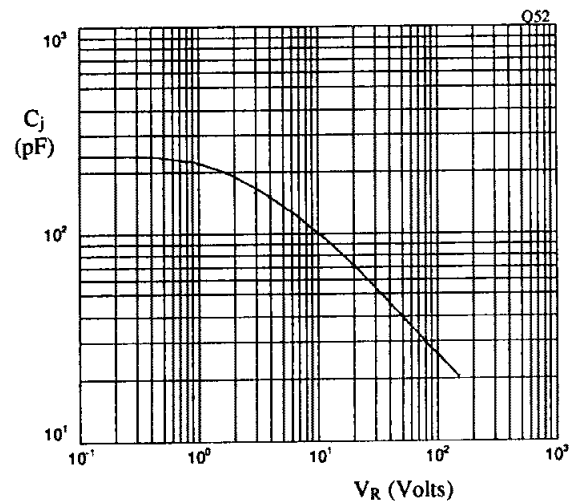


Fig 4. Typical junction capacitance as a function of reverse voltage.

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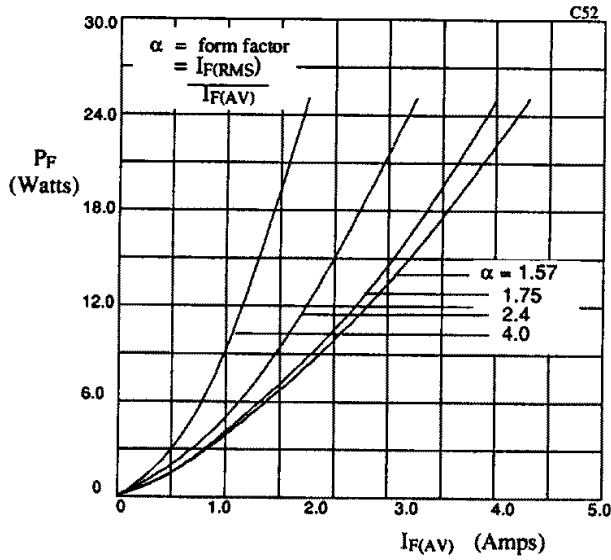


Fig 5. Forward power dissipation as a function of forward current, for sinusoidal operation.

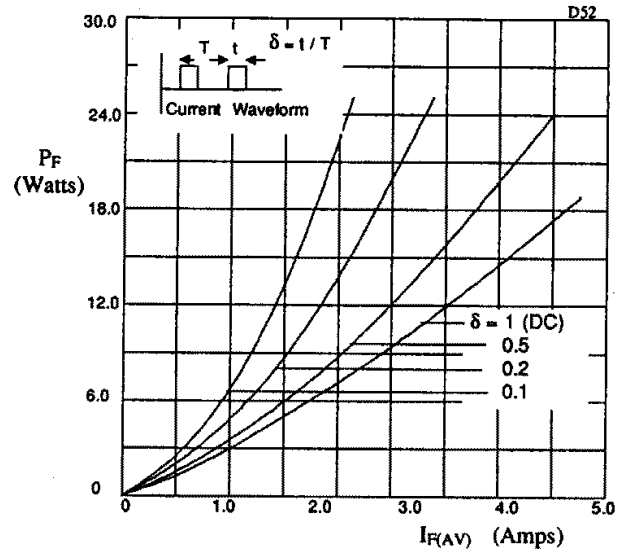


Fig 6. Forward power dissipation as a function of forward current, for square wave operation.

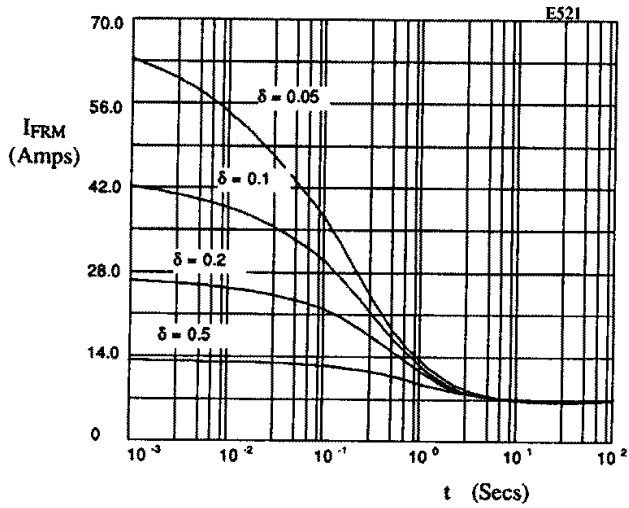


Fig 7. Maximum repetitive forward current as a function of pulse width at 55°C; $R_{\theta JL} = 20 \text{ }^\circ\text{C/W}$; V_{RWM} during $1 - \delta$.

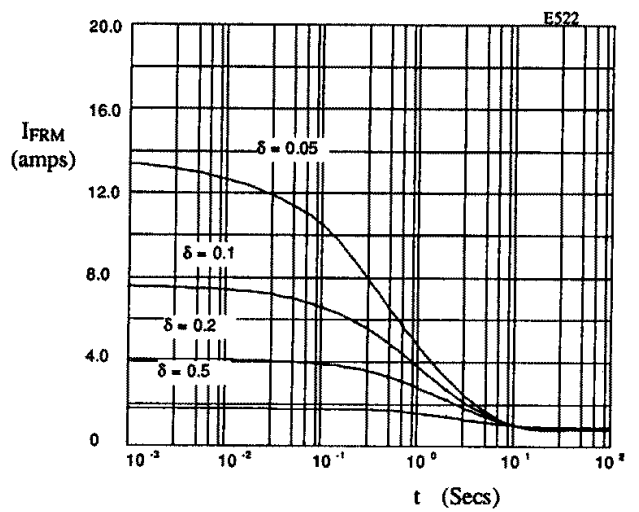


Fig 8. Maximum repetitive forward current as a function of pulse width at 100°C; $R_{\theta JL} = 80 \text{ }^\circ\text{C/W}$; V_{RWM} during $1 - \delta$.